

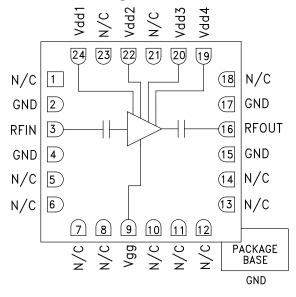


Typical Applications

The HMC634LC4 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- LO Driver for Mixers
- Military & Space

Functional Diagram



HMC634LC4

GaAs PHEMT MMIC DRIVER AMPLIFIER, 5 - 20 GHz

Features

Gain: 21 dB P1dB: +22 dBm Saturated Power: +23 dBm @ 17% PAE Single Supply Voltage: +5V @180 mA 50 Ohm Matched Input/Output 24 Lead 4x4mm SMT Package: 16mm²

General Description

The HMC634LC4 is a GaAs PHEMT MMIC Driver Amplifier in a leadless 4 x 4 mm ceramic surface mount package which operates between 5 and 20 GHz The amplifier provides up to 21 dB of gain, +29 dBm Output IP3, and +22 dBm of output power at 1 dB gain compression, while requiring 180 mA from a +5V supply. The HMC634LC4 is an ideal driver amplifier for microwave radio applications from 5 to 20 GHz, and may be biased at +5V, 130 mA to provide lower gain with optimized PAE. The amplifier's I/Os are DC blocked and matched to 50 Ohms with no external matching required.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd₁₋₄= 5V, Idd= 180 mA^[1]

| Parameter | Min. | Тур. | Max. | Min. | Тур. | Max. | Units |
|---|------|-----------|-------|-------|---------|-------|--------|
| Frequency Range | | 5 - 16 16 | | | 16 - 20 | | GHz |
| Gain | 18 | 21 | | 17 20 | | | dB |
| Gain Variation Over Temperature | | 0.025 | 0.035 | | 0.020 | 0.030 | dB/ °C |
| Input Return Loss | | 18 | | | 14 | | dB |
| Output Return Loss | | 14 | | | 13 | | dB |
| Output Power for 1 dB Compression (P1dB) | 19 | 22 | | 16 | 20 | | dBm |
| Saturated Output Power (Psat) | | 23 | | | 20.5 | | dBm |
| Output Third Order Intercept (IP3) | | 29 | | | 28 | | dBm |
| Noise Figure | | 7.5 | | | 7.5 | | dB |
| Supply Current (Idd) (Idd = $Idd_1 + Idd_2 + Idd_3 + Idd_4$) | | 180 | | | 180 | | mA |

[1] Adjust Vgg between -2 to 0V to achieve Idd= 180 mA Typical.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



HMC634LC4

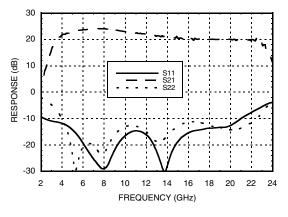
GaAs PHEMT MMIC DRIVER

AMPLIFIER, 5 - 20 GHz

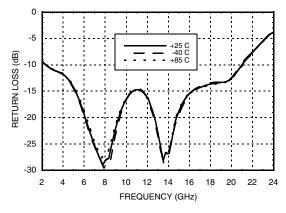
v03.0514



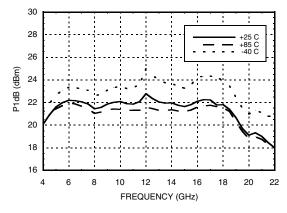
Broadband Gain & Return Loss



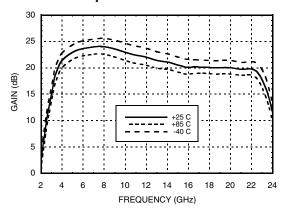
Input Return Loss vs. Temperature



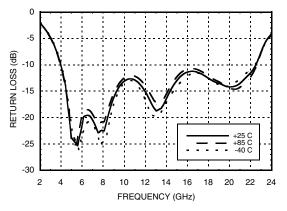
P1dB vs. Temperature



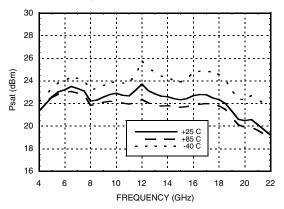
Gain vs. Temperature



Output Return Loss vs. Temperature



Psat vs. Temperature



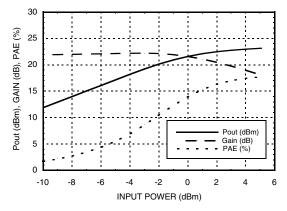
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



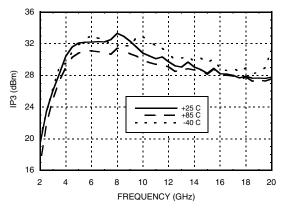
ROHS V EARTH FRIENDLY

Power Compression @ 12.5 GHz

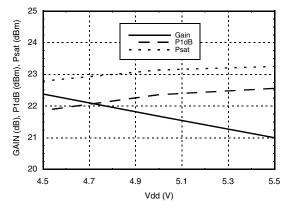
v03.0514



Output IP3 vs. Temperature



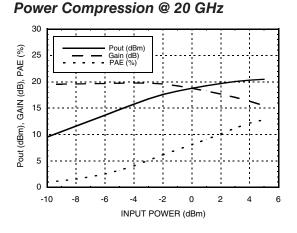
Gain & Power vs. Supply Voltage @ 12.5 GHz



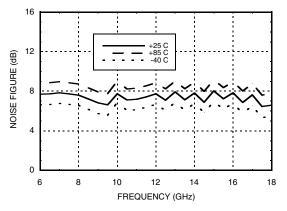
AMPLIFIER, 5 - 20 GHz

GaAs PHEMT MMIC DRIVER

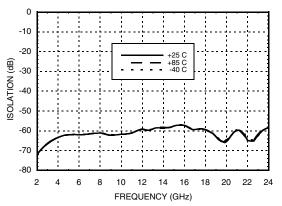
HMC634LC4



Noise Figure vs. Temperature



Reverse Isolation vs. Temperature



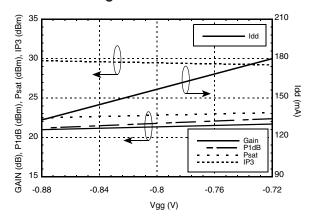
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



HMC634LC4



Gain, Power & Output IP3 vs. Gate Voltage @ 12.5 GHz



Typical Supply Current vs. Vdd

| Vdd (V) | ldd (mA) |
|---------|----------|
| 4.5 | 177 |
| 5.0 | 180 |
| 5.5 | 183 |

Note: Amplifier will operate over full voltage ranges shown above

GaAs PHEMT MMIC DRIVER AMPLIFIER, 5 - 20 GHz

Absolute Maximum Ratings

| Drain Bias Voltage (Vdd1, Vdd2, Vdd3, Vdd4) | +5.5 Vdc |
|---|----------------|
| Gate Bias Voltage (Vgg) | -3 to 0 Vdc |
| RF Input Power (RFIN)(Vdd = +5 Vdc) | +10 dBm |
| Channel Temperature | 175 °C |
| Continuous Pdiss (T= 85 °C) (derate 11.17 mW/°C above 85 °C) | 1 W |
| Thermal Resistance (channel to package bottom) | 89.46 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



HMC634LC4

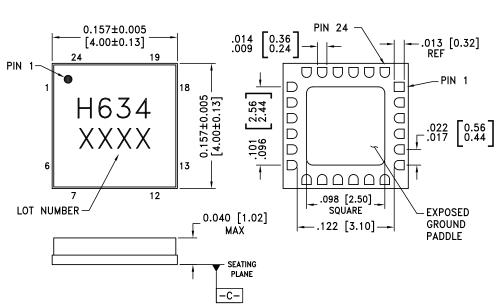
GaAs PHEMT MMIC DRIVER

AMPLIFIER, 5 - 20 GHz

v03.0514



Outline Drawing



BOTTOM VIEW

NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: 30-80
- MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL. 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST

BE SOLDERED TO PCB RF GROUND.

Package Information

| | Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[2] | |
|---|-------------|-----------------------|------------------|---------------------|--------------------------------|--|
| ſ | HMC634LC4 | Alumina, White | Gold over Nickel | MSL3 ^[1] | H634 XXXX | |

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



HMC634LC4

GaAs PHEMT MMIC DRIVER AMPLIFIER, 5 - 20 GHz

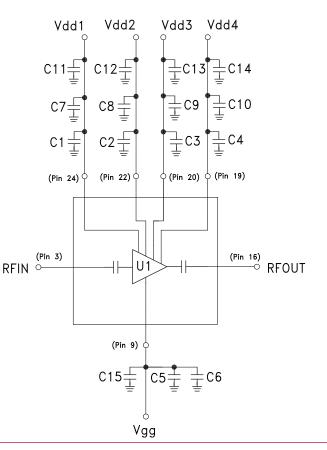


Pin Descriptions

| Pin Number | Function | Description | Interface Schematic | |
|-------------------------------------|---------------------------|--|---------------------|--|
| 1, 5 - 8, 10 - 14, 18, 21, 23 | N/C | The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally. | | |
| 2, 4, 15, 17 | GND | Package Bottom must be connected to RF/DC ground. | | |
| 3 | RFIN | This pin is AC coupled and matched to 50 Ohms. | | |
| 9 | Vgg | Gate control for amplifier, please follow "MMIC Amplifier Biasing Procedure" Application Note: See application circuit for required external components. | Vgg | |
| 16 | RFOUT | This pin is AC coupled and matched to 50 Ohms. | | |
| 24, 22, 20, 19 | Vdd1, Vdd2, Vdd3, Vdd4 | Power Supply Voltage for the amplifier. See application circuit for required external components. | Vdd1,2,3,4 | |

Application Circuit

| Component | Value |
|-----------|---------|
| C1 - C5 | 100 pF |
| C6 - C10 | 1000 pF |
| C11 - C15 | 2.2 µF |



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



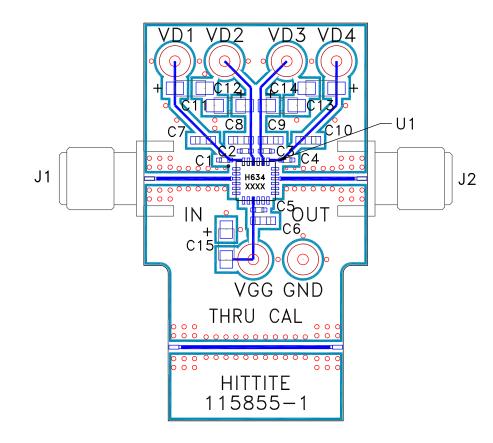
HMC634LC4

v03.0514

GaAs PHEMT MMIC DRIVER AMPLIFIER, 5 - 20 GHz



Evaluation PCB



List of Materials for Evaluation PCB 115857 [1]

| Item | Description |
|-----------|------------------------------|
| J1 - J2 | 2.92 mm PC Mount K-Connector |
| VD1 - VD4 | DC Pin |
| C1 - C5 | 100 pF Capacitor, 0402 Pkg. |
| C6 - C10 | 1000 pF Capacitor, 0603 Pkg. |
| C11 - C15 | 2.2 µF Capacitor, Tantalum |
| U1 | HMC634LC4 Driver Amplifier |
| PCB [2] | 115855 Evaluation PCB |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



HMC634LC4

GaAs PHEMT MMIC DRIVER AMPLIFIER, 5 - 20 GHz



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.